

NEIFELD IP LAW, P.C.
4813-B Eisenhower Avenue
Alexandria, Virginia 22304



Tel: 703-415-0012
Fax: 703-415-0013
Email: rneifeld@Neifeld.com
Web: www.Neifeld.com

IFW

**37 CFR 1.7(c) FILING RECEIPT AND
TRANSMITTAL LETTER WITH
AUTHORIZATION TO CHARGE DEPOSIT ACCOUNT**

Neifeld Docket No.: OSEMDB15UPCTUS

Client Ref.:

US/PCT Application/Patent No.: 10/579,537

US/PCT File/Issue Date: 5/16/2006

Priority Data: US04/38582 filed 11/17/2004

USPTO Confirmation No.: unknown

Inventor: BRADDOCK

Title: Nitride Metal Oxide Semiconductor Integrated Transistor Devices

**THE FOLLOWING HAS BEEN RECEIVED IN THE U.S. PATENT OFFICE ON
THE DATE STAMPED HEREON:**

37 CFR 1.7(c) Filing Receipt and Transmittal Letter with Authorization to Charge Deposit Account (1 page in duplicate)
37 CFR 1.115 Preliminary Amendment (5 pages).

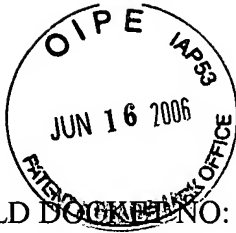
The Commissioner is hereby authorized to charge any fees which may be required, or credit any overpayment, to Deposit Account Number 50-2106. A duplicate copy of this sheet is enclosed.

Respectfully Submitted,

6/15/06
DATE

[Signature]
Richard A. Neifeld
Registration No. 35,299
Attorney of Record

	PcLaw Matter	Lawyer	Amount	Explanation	Date Entered	Initials
Fees:						
Fees:						
Disbursements:	PcLaw Matter	G/L Account	Amount	Explanation	Date Entered	Initials
		5010				



NEIFELD DOCKING NO: OSEMDB15UPCTUS

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF: BRADDOCK

APPLICATION NO: UNKNOWN

CONFIRMATION NO:

NATIONAL STAGE OF PCT/US04/38582 filed 11/17/2004

FILED: Herewith

EXAMINER:

GROUP ART UNIT:

TITLE: Nitride Metal Oxide Semiconductor Integrated Transistor Devices

ASSISTANT COMMISSIONER FOR PATENTS

ALEXANDRIA, VA 22313

37 CFR 1.115 PRELIMINARY AMENDMENT

Sir:

Please enter this amendment prior to examining this application.